

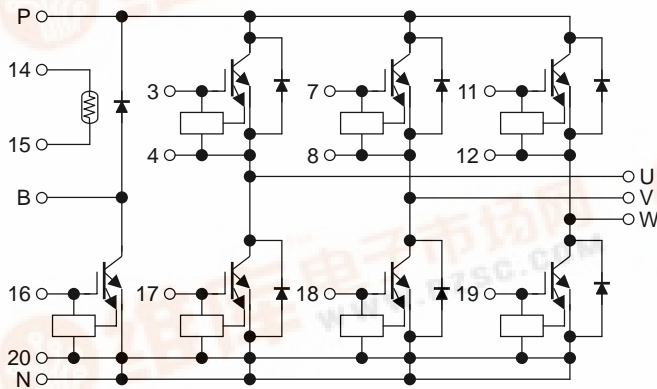
MITSUBISHI IGBT Module

MG150J7KS61 (600V/150A 7in1)

High Power Switching Applications
Motor Control Applications

- Integrates inverter and brake power circuit into a single package
- The electrodes are isolated from case.
- Low thermal resistance
- $V_{CE(sat)} = 1.8\text{ V (typ.)}$

Equivalent Circuit

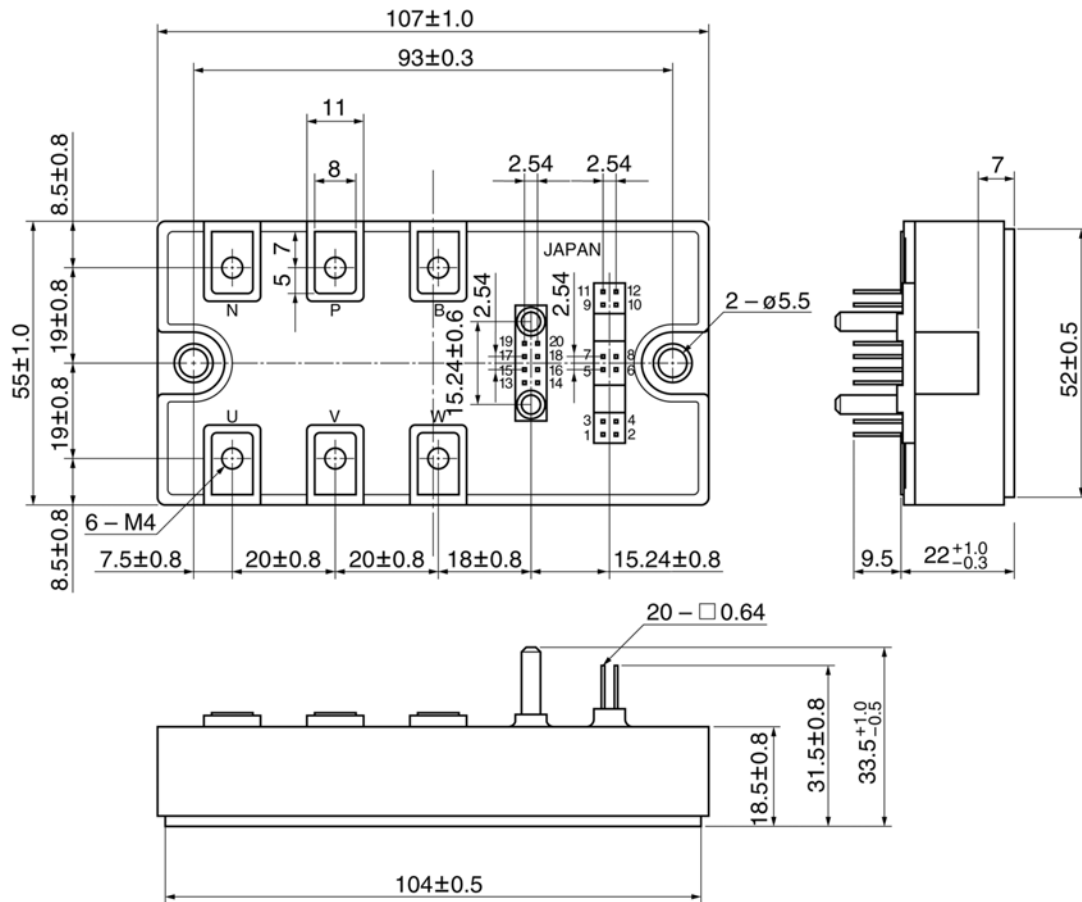


Signal Terminal

1. Open	2. Open	3. G (U)	4. E (U)
5. Open	6. Open	7. G (V)	8. E (V)
9. Open	10. Open	11. G (W)	12. E (W)
13. Open	14. TH1	15. TH2	16. G (B)
17. G (X)	18. G (Y)	19. G (Z)	20. E (L)

Package Dimensions:

Unit: mm



- | | | | |
|-----------|-----------|-----------|-----------|
| 1. Open | 2. Open | 3. G (U) | 4. E (U) |
| 5. Open | 6. Open | 7. G (V) | 8. E (V) |
| 9. Open | 10. Open | 11. G (W) | 12. E (W) |
| 13. Open | 14. TH1 | 15. TH2 | 16. G (B) |
| 17. G (X) | 18. G (Y) | 19. G (Z) | 20. E (L) |

Maximum Ratings (Ta = 25°C)

Stage	Characteristics	Symbol	Rating	Unit	
Inverter	Collector-emitter voltage	V _{CES}	600	V	
	Gate-emitter voltage	V _{GES}	±20	V	
	Collector current	DC	I _C	150	A
		1 ms	I _{CP}	300	
	Forward current	DC	I _F	150	A
		1 ms	I _{FM}	300	
Collector power dissipation (T _c = 25°C)		P _C	750	W	
Brake	Collector-emitter voltage	V _{CES}	600	V	
	Gate-emitter voltage	V _{GES}	±20	V	
	Collector current	DC	I _C	75	A
		1 ms	I _{CP}	150	
	Collector power dissipation (T _c = 25°C)		P _C	375	W
	Reverse voltage		V _R	600	V
	Forward current	DC	I _F	75	A
1 ms		I _{FM}	150		
Module	Junction temperature		T _j	150	°C
	Storage temperature range		T _{stg}	-40~125	°C
	Isolation voltage		V _{isol}	2500 (AC 1 min)	V
	Screw torque	Terminal	—	2 (M4)	N·m
Mounting		—	3 (M5)		

Electrical Characteristics (T_j = 25°C)

1. Inverter stage

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	I _{GES}	V _{GE} = ±20 V, V _{CE} = 0	—	—	±500	nA	
Collector cut-off current	I _{CES}	V _{CE} = 600 V, V _{GE} = 0	—	—	1.0	mA	
Gate-emitter cut-off voltage	V _{GE (off)}	V _{CE} = 5 V, I _C = 150 mA	5.0	6.5	8.0	V	
Collector-emitter saturation voltage	V _{CE (sat)}	V _{GE} = 15 V, I _C = 150 A	T _j = 25°C	—	1.8	2.3	V
			T _j = 125°C	—	—	2.5	
Input capacitance	C _{ies}	V _{CE} = 10 V, V _{GE} = 0, f = 1 MHz	—	30000	—	pF	
Switching time	Turn-on delay time	t _{d (on)}	V _{CC} = 300 V, I _C = 150 A V _{GE} = ±15 V, R _G = 15 Ω (Note 1)	—	—	1.00	μs
	Turn-off time	t _{off}		—	—	1.20	
	Fall time	t _f		—	—	0.50	
Reverse recovery time	t _{rr}		—	—	0.30		
Forward voltage	V _F	I _F = 150 A	—	2.4	2.8	V	

Note 1: Switching time test circuit & timing chart

2. Brake stage

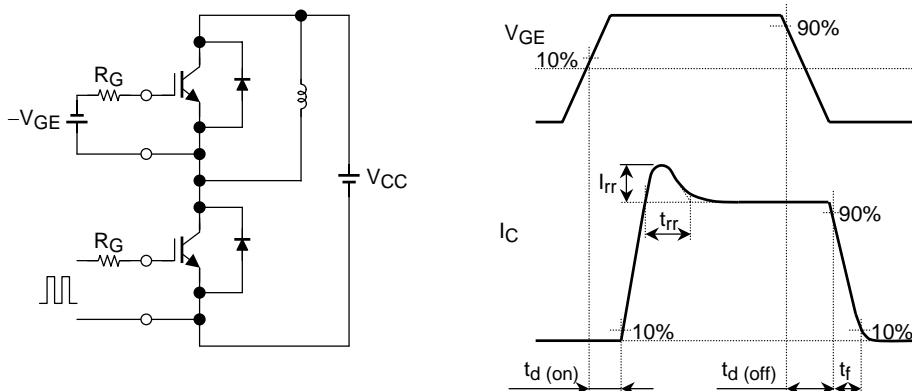
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	I_{GES}	$V_{GE} = \pm 20\text{ V}, V_{CE} = 0$	—	—	± 500	nA	
Collector cut-off current	I_{CES}	$V_{CE} = 600\text{ V}, V_{GE} = 0$	—	—	1.0	mA	
Gate-emitter cut-off voltage	$V_{GE (off)}$	$V_{CE} = 5\text{ V}, I_C = 75\text{ mA}$	5.0	6.5	8.0	V	
Collector-emitter saturation voltage	$V_{CE (sat)}$	$V_{GE} = 15\text{ V}, I_C = 75\text{ A}$	$T_j = 25^\circ\text{C}$	—	1.8	2.2	V
			$T_j = 125^\circ\text{C}$	—	—	2.2	
Input capacitance	C_{ies}	$V_{CE} = 10\text{ V}, V_{GE} = 0, f = 1\text{ MHz}$	—	15000	—	pF	
Switching time	Turn-on delay time	$V_{CC} = 300\text{ V}, I_C = 75\text{ A}$ $V_{GE} = \pm 15\text{ V}, R_G = 24\ \Omega$ (Note 1)	—	—	1.00	μs	
	Turn-off time		—	—	1.20		
	Fall time		—	—	0.50		
Reverse current	I_R	$V_R = 600\text{ V}$	—	—	1.0	mA	
Forward voltage	V_F	$I_F = 75\text{ A}$	—	2.1	2.6	V	

Note 1: Switching time test circuit & timing chart

3. Module ($T_c = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Zero-power resistance	R25	$I_{TM} = 0.2\text{ mA}$	—	100	—	$\text{k}\Omega$
B value	B25/85	$T_c = 25^\circ\text{C}/T_c = 85^\circ\text{C}$	—	4390	—	K
Junction to case thermal resistance	$R_{th (j-c)}$	Inverter IGBT stage	—	—	0.167	$^\circ\text{C/W}$
		Inverter FRD stage	—	—	0.313	
		Brake IGBT stage	—	—	0.333	
		Brake FRD stage	—	—	1.000	
Case to fin thermal resistance	$R_{th (c-f)}$	—	—	0.017	—	$^\circ\text{C/W}$

Switching Time Test Circuit & Timing Chart



Recommended conditions for application

Characteristics	Symbol	Min	Typ.	Max	Unit
P-N power terminal supply voltage	V_{CC}	—	300	400	V
Gate voltage	V_{GE}	13.5	15	16.5	V
Switching frequency	f_c	—	—	20	kHz